

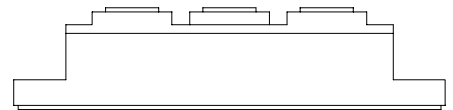
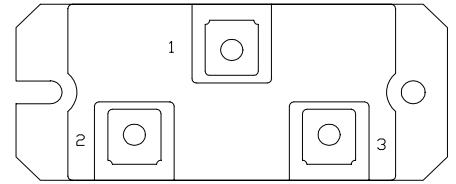
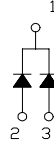
FRD MODULE 100A/500V/trr:100nsec

PC100F5

OUTLINE DRAWING

FEATURES

- * Isolated Base
- * Dual Diode Cathode Common
- * Ultra Fast Recovery
- * High Surge Capability
- * UL Recognized, File No. E187184



TYPICAL APPLICATIONS

- * High Frequency Rectification

Maximum Ratings

Approx Net Weight:210g

Voltage Rating	Symbol	PC100F5		Unit
Repetitive Peak Reverse Voltage per Arm	V_{RRM}	500		V
Electrical Rating		Condition	Rating	
Average Rectified Output Current	I_o	50Hz Half Sine Wave condition per Arm $T_c=84^\circ\text{C}$	100	A
RMS Forward Current	$I_{F(RMS)}$	per Arm	157	A
Surge Forward Current	I_{FSM}	50 Hz Half Sine Wave, 1 cycle Non-repetitive per Arm	1800	A
I Squared t	I^2t	2 msec to 10 msec per Arm	16200	A^2s
Operating Junction Temperature Range	T_{jw}		-40 to +150	$^\circ\text{C}$
Storage Temperature Range	T_{stg}		-40 to +125	$^\circ\text{C}$
Isolation Voltage	V_{iso}	Base Plate to Terminal, AC 1min	2000	V
Mounting torque	F_{tor}	Case mounting(recommended)	2.6	N·m
		Terminal Screw(recommended)	1.4	

Electrical • Thermal Characteristics

Characteristics	Symbol	Test Conditions	Max.	Unit
Peak Forward Voltage	V_{FM}	$I_{FM}= 100\text{A}$, $T_j=25^\circ\text{C}$, per Arm	1.35	V
Peak Reverse Current	I_{RM}	$V_{RM}= V_{RRM}$, $T_j= 150^\circ\text{C}$, per Arm	10	mA
Reverse Recovery Time	trr	$I_{FM}= 10\text{A}$, $-di/dt= 50 \text{ A}/\mu\text{s}$, $T_a= 25^\circ\text{C}$ Per Arm	100	ns
Thermal Resistance	$R_{th(j-c)}$	Junction to Case per Arm	0.5	$^\circ\text{C}/\text{W}$
	$R_{th(c-f)}$	Base Plate to Heat Sink with Thermal Compound	0.1	
Internal Lead Inductance	L_s	Anode Terminal to Cathode Terminal Per Element	30	nH

PC100F5 OUTLINE DRAWING (Dimensions in mm)

